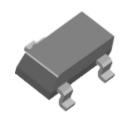
P - Channel Logic Level MOSFET

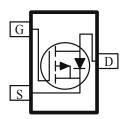
These miniature surface mount MOSFETs utilize High Cell Density process. Low $r_{DS(on)}$ assures minimal power loss and conserves energy, making this device ideal for use in power management circuitry. Typical applications are voltage control small signal switch, power management in portable and battery-powered products such as computer portable electronics and other battery power application.

•	Low $r_{DS(on)}$ Provides Higher Efficiency and
	Extends Battery Life

- Fast Switch
- Low Gate Charge
- Miniature SOT-23 Surface Mount Package Saves Board Space

PRODUCT SUMMARY				
$V_{DS}(V)$	$\mathbf{r}_{\mathrm{DS(on)}}\left(\Omega\right)$	$I_{D}(A)$		
-30	$0.20 @ V_{GS} = -10 V$	-2.1		
-30	$0.30 @ V_{GS} = -4.5V$	-1.7		





2SJ204

ABSOLUTE MAXIMUM RATINGS (T _A = 25 °C UNLESS OTHERWISE NOTED)					
Parameter			Maximum	Units	
Drain-Source Voltage			-30	V	
Gate-Source Voltage			±20	V	
	$T_A=25^{\circ}C$	T	-2.1		
Continuous Drain Current ^a	$T_{A}=25^{\circ}C$ $T_{A}=70^{\circ}C$	1D	-1.7	A	
Pulsed Drain Current ^b		I_{DM}	±10		
Continuous Source Current (Diode Conduction) ^a		I_S	-0.4	A	
D D: a	$T_{A}=25^{\circ}C$ $T_{A}=70^{\circ}C$		1.25	W	
Power Dissipation ^a	$T_A=70^{\circ}C$	LD	0.8	vv	
Operating Junction and Storage Temperature Range		T_{J}, T_{stg}	-55 to 150	°C	

THERMAL RESISTANCE RATINGS						
Parameter		Symbol	Maximum	Units		
M . I	t <= 5 sec	D	250	0C/M		
Maximum Junction-to-Ambient ^a	Steady-State	R_{THJA}	285	°C/W		

1

Notes

- a. Surface Mounted on 1" x 1" FR4 Board.
- b. Pulse width limited by maximum junction temperature

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D	Symbol	T	Limits			TT
Parameter		Test Conditions	Min	Тур	Max	Unit
Static						
Zero Gate Voltage Drain Current	IDSS	$V_{DS} = -24 \text{ V}, V_{GS} = 0 \text{ V}$			-1	μΑ
Zero Gate Voltage Diain Current	1088	$V_{DS} = -24 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 55^{\circ}\text{C}$			-10	
Gate-Body Leakage	Igss	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$			±100	nA
Gate-Threshold Voltage	V _{GS(th)}	$V_{\rm DS} = V_{\rm GS}, I_{\rm D} = -250 {\rm uA}$	-1.30			V
On-State Drain Current ^A	I _{D(on)}	$V_{DS} = -5 \text{ V}, V_{GS} = -4.5 \text{ V}$	-3			Α
D : G . C . D : A	_	$V_{GS} = -10 \text{ V}, I_D = -2.1 \text{ A}$			0.20	Ω
Drain-Source On-Resistance ^A	fDS(on)	$V_{GS} = -4.5 \text{ V}, I_D = -1.7 \text{ A}$			0.30	
Forward Tranconductance ^A	gs	$V_{DS} = -5 \text{ V}, I_D = -2.1 \text{ A}$		2		S
Diode Forward Voltage	Vsd	$I_S = -0.4 \text{ A}, V_{GS} = 0 \text{ V}$		-0.70	-1.2	V
Dynamic ^b						
Total Gate Charge	Qg	Voc = 10 V Voc = 5 V		3.4		nC
Gate-Source Charge	Qgs	$V_{DS} = -10 \text{ V}, V_{GS} = -5 \text{ V},$ $I_{D} = -2.1 \text{ A}$		0.8		
Gate-Drain Charge	Q_{gd}	ID2.1 A		1.5		
Turn-On Delay Time	t _{d(on)}			8		
Rise Time	tr	$V_{DS} = -10 \text{ V}, I_{D} = -1.1 \text{ A},$		18		ns
Turn-Off Delay Time	t _{d(off)}	$R_G = 50 \Omega$, $V_{GEN} = -10 V$		52		1115
Fall-Time	t_{f}			39		

Notes

- a. Pulse test: $PW \le 300us duty cycle \le 2\%$.
- b. Guaranteed by design, not subject to production testing.

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Typical Electrical Characteristics

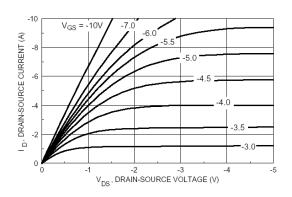


Figure 1. On-Region Characteristics

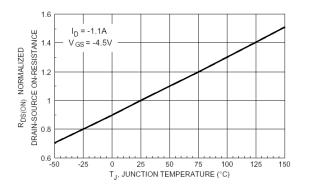


Figure 3. On-Resistance Variation with Temperature

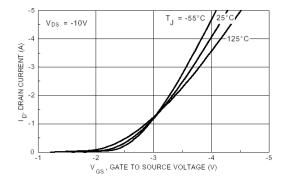


Figure 5. Transfer Characteristics

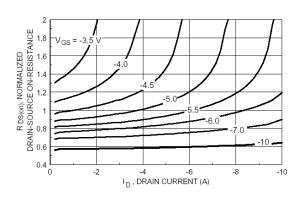


Figure 2. On-Resistance Variation with Drain Current and Gate Voltage

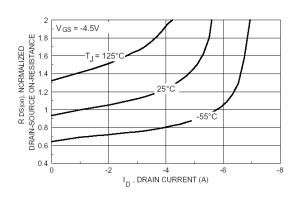


Figure 4. On-Resistance Variation with Gate to Source Voltage

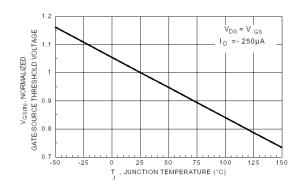


Figure 6. Body Diode Forward Voltage Variation with Source Current and Temperature

Freescale 2SJ204

Typical Electrical Characteristics

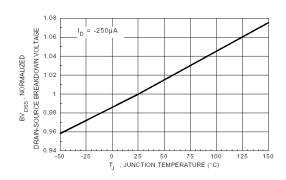


Figure 7. Breakdown Voltage Variation with Temperature.

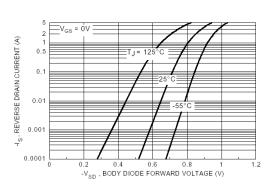


Figure 8. Body Diode Forward Voltage Variation with Source Current and Temperature.

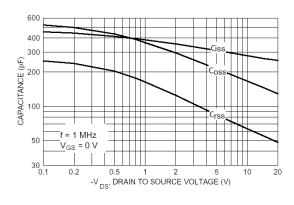


Figure 9. Capacitance Characteristic

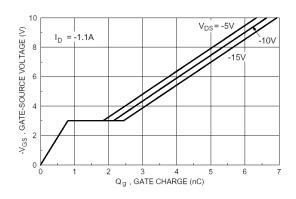


Figure 10. Gate Charge Characteristic

Normalized Thermal Transient Impedance, Junction to Ambient

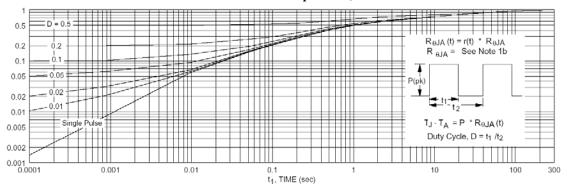


Figure 11. Transient Thermal Response Curve

Typical Electrical Characteristics

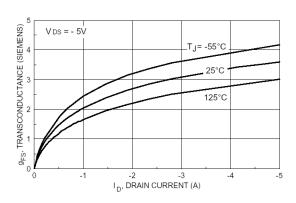
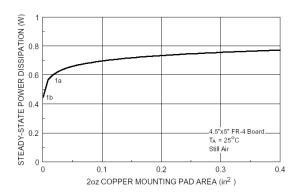


Figure 12. Transconductance Variation With Current & Temperature

Figure 13. Maximum Safe Operation Area



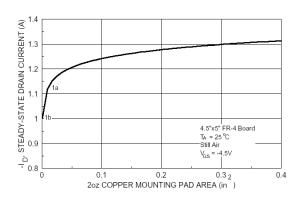


Figure 14. SOT-3 Maximum Steady-State Variation Power Dissipation versus Copper Pad Area

Figure 15. Maximum State-State Drain Current Versus Copper Pad Area

Package Information

